





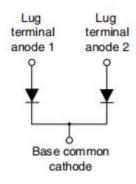
309CNQ135/309CNQ150 SCHOTTKY RECTIFIER



Features

- 175[°]C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- · enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- The terminal hardware is supplied with the module.
- The mounting hardware is not supplied. Recommended is the use of 1/4-20 or M6 screws with spring washer.
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	135	309CNQ135	V
DC Blocking Voltage	V RWM VR		150	309CNQ150	v
Average Rectified Forward Current		50% duty cycle @T _C =110°C,	150(Per Leg)		A
Average Nectified Forward Current		rectangular wave form	300(Per Device)		
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	1440		А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 150A, Pulse, T _J = 25 °C @ 300A, Pulse, T _J = 25 °C	0.83 0.93	1.03 1.22	V
	V _{F2}	@ 150A, Pulse, T _J = 125 °C @ 300A, Pulse, T _J = 125 °C	0.72 0.79	0.76 0.82	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.06	3	mA
	I _{R2}	$@V_R = \text{rated } V_{R_i} T_J = 125 ^{\circ}\text{C}$	3.40	45	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2990	4000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

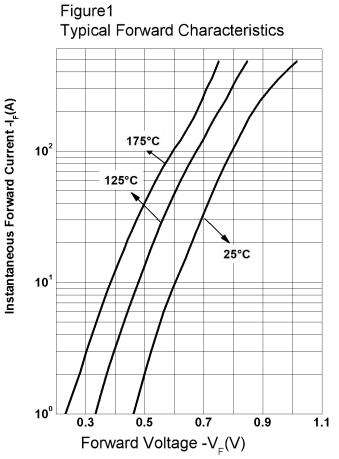
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T _{stg}	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	R _θ JC	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	R _θ JC	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.08		°C/W
Mounting Torque	Тм	-	Mounting Torque	3.84(min) 4.80(max)	- Nm
			Terminal Torque	2.35(min) 3.43(max)	
Approximate Weight	wt	-	91		g
Case Style		PRM4 Non-Isolated			

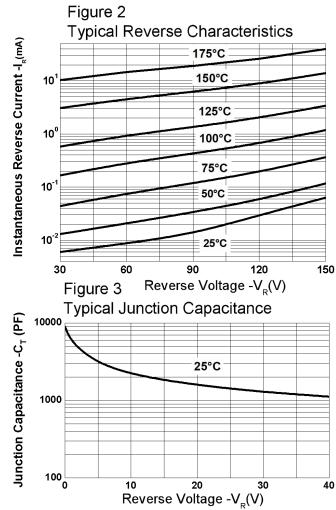






Ratings and Characteristics Curves



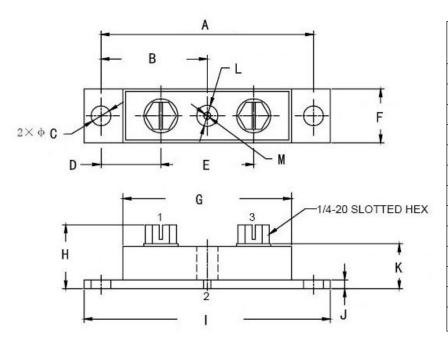






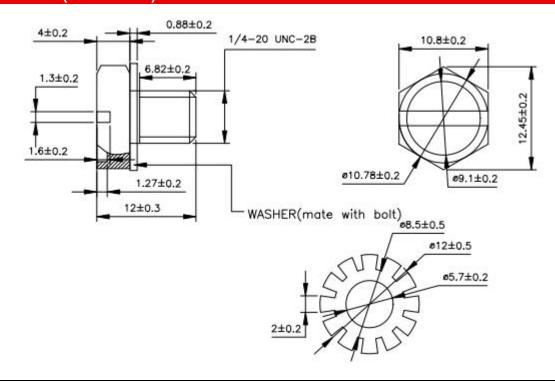


Mechanical Dimensions PRM4 Non-Isolated (Millimeters/Inches)



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	78.74	81.28	3.100	3.200	
В	37.47	42.55	1.475	1.675	
С	6.89	7.69	0.271	0.303	
D	19.51	24.59	0.768	0.968	
E	33.02	38.10	1.300	1.500	
F	17.78	20.32	0.700	0.800	
G	60.96	64.77	2.400	2.550	
Н	17.26	23.25	0.680	0.915	
I	90.17	92.71	3.550	3.650	
J	3.02	3.68	0.119	0.145	
K	14.30	16.15	0.563	0.636	
L	9.27	10.79	0.365	0.425	
М	4.37	5.28	0.172	0.208	

1/4-20 screws (Millimeters)



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